

# Atomic-scale design of light-absorbing materials (or can computing compete with chemical intuition?)



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## Overview

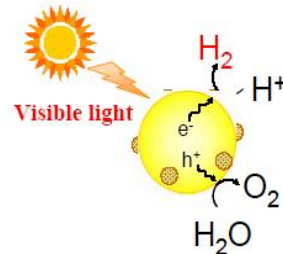


- Intro about water splitting
- Methodology (DFT and friends)
  - Material stabilities vs standard states and beyond
  - Pourbaix diagrams
  - Bandgaps and light absorption
- One-photon water splitting
- Tandem cells
- Water protection layers
- Materials
  - Perovskites
    - Oxides, oxynitrides, oxysulfides, oxyfluorides, OFN
    - Double perovskites
    - Layered perovskites (Ruddlesden-Popper)
    - Organic halide perovskites
  - Inorganic crystal structure database (ICSD)
- Outlook

## Light absorption and water splitting



Computational search for materials able to collect the visible part of the solar spectrum and to use the energy to split water in oxygen and hydrogen.



Complicated process:

- Light absorption
- Electron-hole motion
- Induce reactions

Examples:  $\text{TiO}_2$ ,  $\text{GaN}:\text{ZnO}$ ,  $\text{ZnGeN}_2:\text{ZnO}$



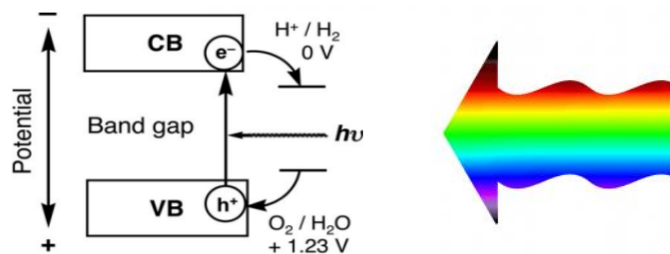
(Fujishima and Honda, *Nature* 1972)

(Maeda et al., *JACS*, **127**, 8286 (2005), Domen group)

## Materials for water splitting



- Chemical/structural stability
- Band gap of 1.5-3 eV (overpotentials, losses)
- Band edge positions straddle the water redox potentials
- Good electron/hole mobilities
- Good catalytic properties
- Low cost, non-toxicity

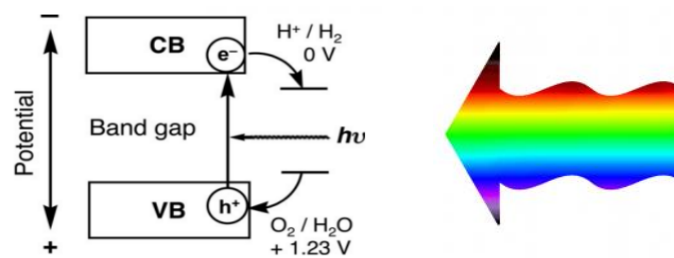


Principle of water splitting using semiconductor photocatalysts.

## Materials for water splitting



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Principle of water splitting using semiconductor photocatalysts.

## Methodology – density functional theory + friends



### GPAW – projector augmented wave method in real space



J. Enkovaara *et al.* J. Phys.:Cond. Mat. **22** (2010) ← **Review article**

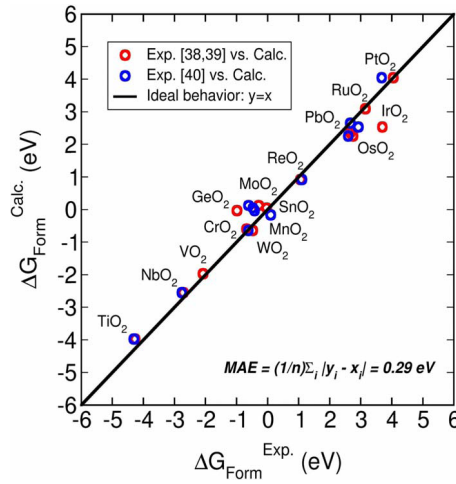
<https://wiki.fysik.dtu.dk/gpaw/> ← **Free download, GPL**

- ❑ High accuracy: Wave functions expanded on real space grids or plane waves
- ❑ High efficiency: Wave functions expanded in atomic-like orbitals (LCAO)
- ❑ Efficient parallelization (good scalability up to > 32.000 CPUs)
- ❑ Xc-functionals: LDA, GGAs, meta-GGA, LDA+U, EXX, vdWDF, GLLB, BEEF
- ❑ Time-dependent DFT (including “Bootstrap”)
- ❑ Many-body perturbation theory (GW and Bethe-Salpeter equation)
- ❑ Phonons and electron-phonon coupling
- ❑ Quantum electron transport
- ❑ Atomic Simulation Environment (ASE) python scripting interface

# Predicting stability of oxides



- Oxides highly relevant because of high stability (towards oxidation!)
- DFT-RPBE calculated formation energy for rutile dioxides.
- Similar results obtained for perovskite structures.

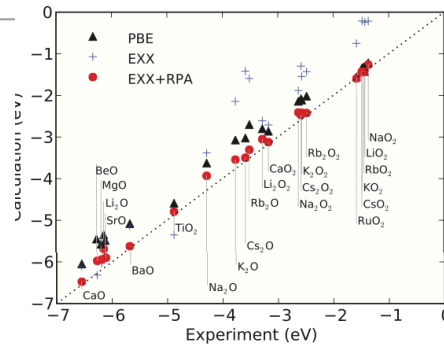


J. I. Martínez *et al.*, Phys. Rev B 2009

# Predicting stability of oxides (II)



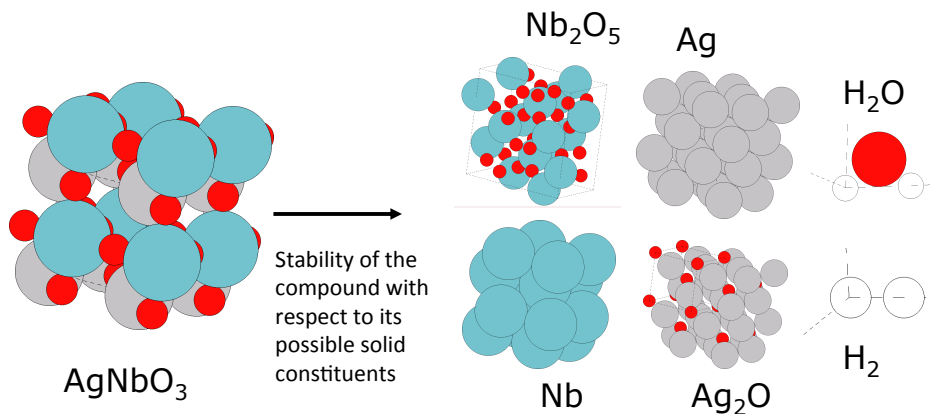
	PBE	EXX	EXX + RPA@PBE
Li <sub>2</sub> O	-5.35	-5.72	-5.69
Li <sub>2</sub> O <sub>2</sub>	-2.80	-2.61	-3.05
LiO <sub>2</sub>	-1.42	-0.24	-1.38
Na <sub>2</sub> O	-3.62	-3.38	-3.93
Na <sub>2</sub> O <sub>2</sub>	-2.14	-1.88	-2.41
NaO <sub>2</sub>	-1.22	-0.22	-1.26
K <sub>2</sub> O	-3.07	-2.14	-3.54
K <sub>2</sub> O <sub>2</sub>	-2.11	-1.55	-2.42
KO <sub>2</sub>	-1.34	-0.21	-1.45
Rb <sub>2</sub> O	-2.70	-1.59	-3.30
Rb <sub>2</sub> O <sub>2</sub>	-2.02	-1.43	-2.42
RbO <sub>2</sub>	-1.31	0.12	-1.43
Cs <sub>2</sub> O	-3.02	-1.42	-3.50
Cs <sub>2</sub> O <sub>2</sub>	-2.08	-1.30	-2.47
CsO <sub>2</sub>	-1.36	0.15	-1.43
BeO	-5.45	-6.31	-5.89
MgO	-5.57	-6.04	-5.94
CaO	-6.05	-6.10	-6.48
CaO <sub>2</sub>	-2.86	-2.71	-3.12
SrO	-5.49	-5.51	-5.90
BaO	-5.08	-5.14	-5.62
TiO <sub>2</sub>	-4.59	-5.35	-4.79
RuO <sub>2</sub>	-1.56	-0.75	-1.59
MAE	0.44	0.96	0.15
MAE <sub>S</sub>	0.21		0.10



Shifted O reference

Yan, Hummelshøj, and Nørskov, PRB 87, 075207 (2013)

## Stability vs other solid phases



## Stability vs other solid phases



**Example:** Stability of perovskite  $ABO_3$

**Pool of reference systems:**

- Single metal bulk:  $A(s)$  and  $B(s)$
  - Single metal oxides:  $A_xO_y(s)$  (and later nitrides, sulfides, ...)
  - Bimetallic oxides  $A_xB_yO_z(s)$ 
    - Composition and structure available experimentally
    - Energy calculated
- Obtained from ICSD

Oxygen is taken from water (and hydrogen molecule)

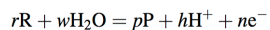
Formation energy:

$$\Delta E = ABO_3(s) - \min_{c_i} (c_1A(s) + c_2B(s) + c_3A_xO_y(s) + c_4B_xO_y(s) + c_5O)$$

$$c_1 + c_3 = 1, \quad c_2 + c_4 = 1, \quad c_3 + c_4 + c_5 = 3$$

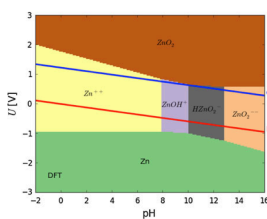
→ Solved by linear programming.

# Stability vs dissolution in water – Pourbaix diagrams

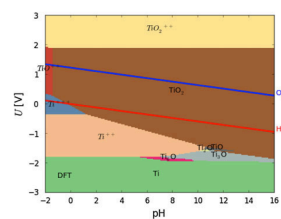


- Using the Nernst equation  

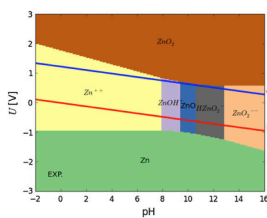
$$nE = \Delta G + 0.0591 \log \frac{(a_P)^p}{(a_R)^r} - 0.0591h \text{ pH}$$
- Free energies of dissolved species taken from expt.



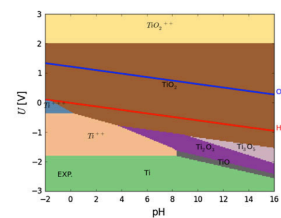
(a) ZnO - DFT



(b) TiO<sub>2</sub> - DFT



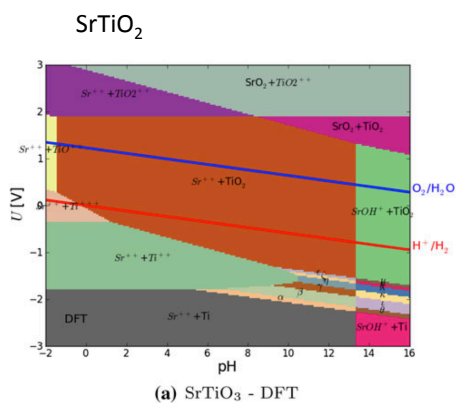
(c) ZnO - Experiments



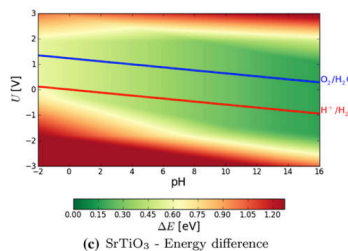
(d) TiO<sub>2</sub> - Experiments

K. A. Persson et al. Phys Rev B **85**, 235438 (2012)  
 I. E. Castelli, K. S. Thygesen, K. W. Jacobsen, Top Catal **57**, 265 (2013)

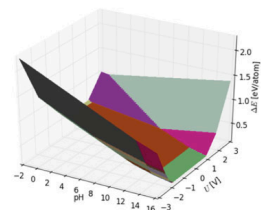
# Stability vs dissolution in water – Pourbaix diagrams (II)



(a) SrTiO<sub>3</sub> - DFT



(c) SrTiO<sub>3</sub> - Energy difference



(e) SrTiO<sub>3</sub> - 3D convex hull

The cubic perovskite phase never most stable.  
 Known to exist experimentally -> metastability, kinetics

I. E. Castelli, K. S. Thygesen, K. W. Jacobsen, Top Catal **57**, 265 (2013)

## The bandgap in density functional theory



- ◆ DFT is aimed at calculating ground state total energies
- ◆ Kohn-Sham states describe the density of a non-interacting electron gas
- ◆ But the quasiparticle gap can be determined as a total energy difference for different number of particles
  - ◆ Works well with LDA/GGA for molecules
  - ◆ Does not work with LDA/GGA for semiconductors

## Calculated ionization potentials for small molecules



Molecule	Expt. <sup>a</sup>	PBE-eig	PBE0-eig	HF-eig	GW	G <sub>0</sub> W <sub>0</sub> (HF)	G <sub>0</sub> W <sub>0</sub> (PBE)-QP	MP2 <sup>a</sup>	PBE-tot
LiH	7.90	4.34	5.81	8.14	8.0 <sup>b</sup>	8.2 <sup>b</sup>	8.0	8.20	8.02
Li <sub>2</sub>	5.11	2.96	3.62	4.62	4.6	4.7	4.4	4.91	5.09
LiF	11.30	6.00	8.62	13.26	11.7	11.2	12.0	12.64	11.87
Na <sub>2</sub>	4.89	2.81	3.38	4.16	4.1	4.3	4.7	4.48	4.97
○ ○ ○ 34 molecules									
P <sub>2</sub>	10.62	7.09	8.21	9.65	9.2	9.8	9.0	10.09	10.37
SiH <sub>4</sub>	12.30	8.50	10.13	12.93	12.3	12.6	12.4 <sup>c</sup>	13.25	11.95
Si <sub>2</sub> H <sub>6</sub>	10.53	7.27	8.54	10.82	10.2	10.6	9.9	11.03	10.36
SiO	11.49	7.46	9.14	11.78	10.9	11.2	11.3	11.82	11.27
MAE		4.35	2.55	0.81	0.5	0.4	0.5	0.82	0.24

DFT Kohn-Sham spectrum

Many-body  
perturbation  
theory

DFT total  
energies

However, DFT-LDA/PBE total energies cannot be used for semiconductor bandgaps.

KS gap + derivative discontinuity!

(C. Rostgaard, K. W. Jacobsen, and K. S. Thygesen, PRB 2010)

# Bandgap calculations with GLLB



The GLLB xc-functional (Gritsenko, van Leeuwen, van Lenthe and Baerends):

$$E_g^{QP} = E_g^{KS} + \Delta_{xc}$$

Derivative discontinuity

$$v_x(\mathbf{r}) = v_S(\mathbf{r}) + v_{\text{resp}}(\mathbf{r})$$

$$v_S(\mathbf{r}) = \frac{2\epsilon_x^{\text{GGA}}(\mathbf{r}; n)}{n(\mathbf{r})}$$

$$v_{\text{resp}}(\mathbf{r}) = \sum_{\text{occ}} K[n] \sqrt{\epsilon_r - \epsilon_i} \frac{|\psi_i(\mathbf{r})|^2}{n(\mathbf{r})}$$

$$\Delta_{x,\text{resp}}(\mathbf{r}) = \sum_i^K (\sqrt{\epsilon_{N+1} - \epsilon_i} - \sqrt{\epsilon_N - \epsilon_i}) \frac{|\psi_i(\mathbf{r})|^2}{n(\mathbf{r})}$$

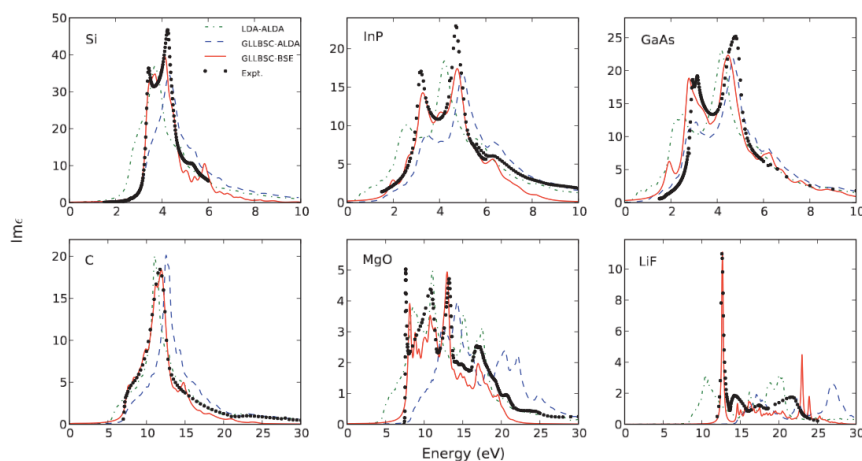
GLLB-SC: Screening exchange-correlation from PBEsol

First description: Gritsenko *et al.*, *Phys. Rev. A* **51**, 1944 (1995).

Implemented in GPAW: Kuisma *et al.*, *Phys. Rev. B* **82**, 115106 (2010).

Material	$E_g^{KS}$ (LDA)	$E_g^{KS}$	$\Delta_{xc}$	$E_g^{QP}$	Exp.
C	4.09	4.14	1.27	5.41	5.48
Si	0.443	0.68	0.32	1.00	1.17
GaAs	0.36	0.79	0.25	1.04	1.63
AlAs	1.34	1.67	0.82	2.49	2.32
LiF	8.775	10.87	4.09	14.96	14.2
Ar	8.18	10.28	4.69	14.97	14.2

# Optical absorption spectra with GLLB-SC

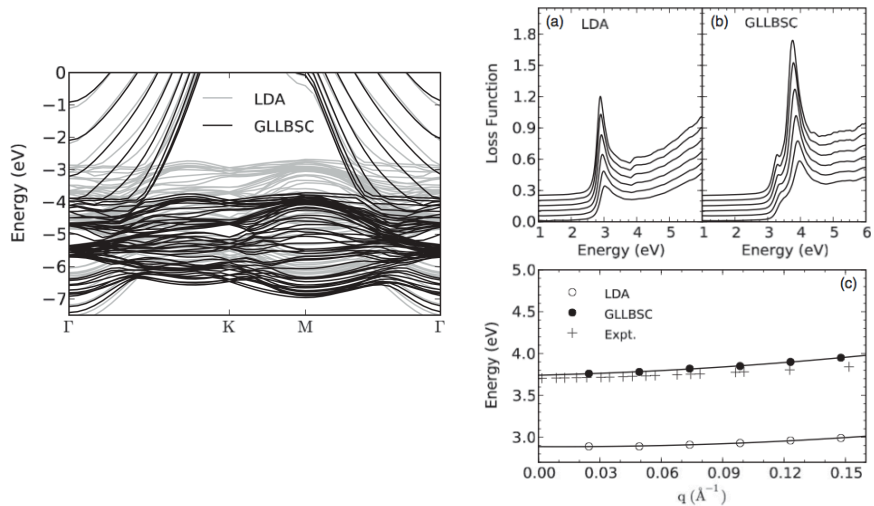


Derivative discontinuity used in spectrum for TDDFT, but not for W in BSE.

J. Yan, K. W. Jacobsen, and K. S. Thygesen, *PRB* **86**, 45208 (2012)



# Ag surface plasmon with GLLB-SC



J. Yan, K. W. Jacobsen, and K. S. Thygesen, PRB **84**, 235430 (2011)

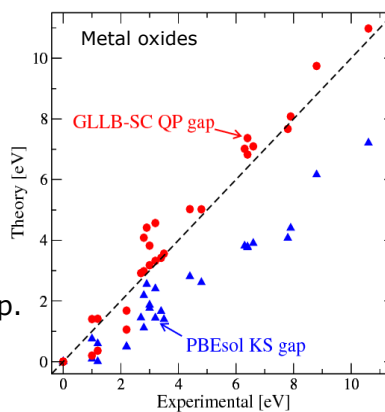
# Predicting bandgaps of oxides with GLLB-SC

The GLLB-SC (solid-correlation) xc-functional:

$$E_g^{QP} = E_g^{KS} + \Delta_{xc}$$

Derivative discontinuity

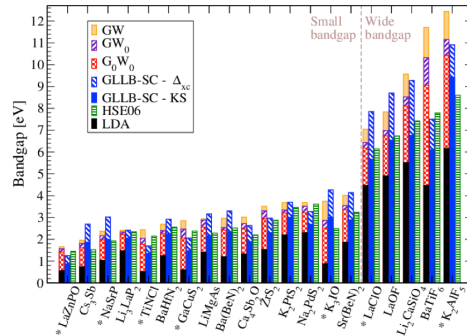
- Bandgaps within ~0.5 eV of exp.
- Minimal computational cost
- Neglect of electron-hole interaction



# Bandgaps for a selection of systems from Inorganic Crystal Structure Database



20 "randomly" selected systems



xc \ xc-ref	LDA	GLLB-SC	HSE06	G <sub>0</sub> W <sub>0</sub>	GW <sub>0</sub>	GW
LDA	—	1.64 (-1.64)	1.21 (-1.21)	1.14 (-1.14)	1.37 (-1.37)	1.67 (-1.67)
GLLB-SC	1.64 (1.64)	—	0.61 (0.43)	0.53 (0.50)	0.50 (0.27)	0.41 (0.03)
HSE06	1.21 (1.21)	0.61 (-0.43)	—	0.19 (0.07)	0.23 (-0.16)	0.46 (-0.46)
G <sub>0</sub> W <sub>0</sub>	1.14 (1.14)	0.53 (-0.50)	0.19 (-0.07)	—	0.24 (-0.24)	0.53 (-0.53)
GW <sub>0</sub>	1.37 (1.37)	0.50 (-0.27)	0.23 (0.16)	0.24 (0.24)	—	0.30 (-0.30)
GW	1.67 (1.67)	0.41 (-0.03)	0.46 (0.46)	0.53 (0.53)	0.30 (0.30)	—

Small bandgap systems

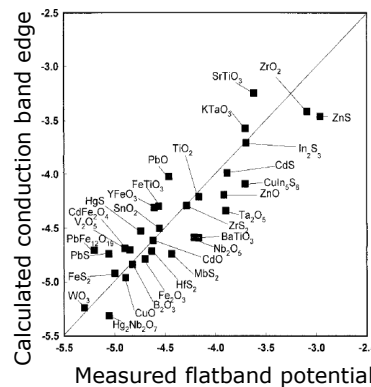
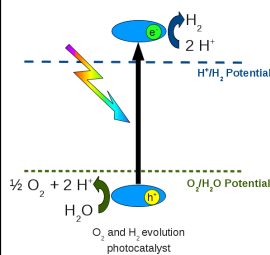
(Collaboration with Materials Project)

Castelli, Hüser, Pandey, Li, Seger, Thygesen, Jain, Persson, Ceder, Jacobsen, in preparation.

# Band edge positions



Empirical formula:  $E_C = (\chi_A \chi_B \chi_O^3)^{1/5} - 1/2 E_{gap} + E_0$



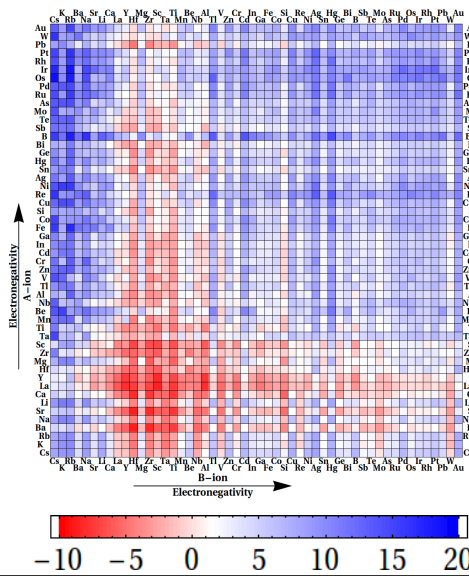
$X = 1/2(A + I_1) =$   
Absolute electronegativity (Mulliken scale)  
 $A =$  Affinity level  
 $I_1 =$  Ionization level  
 $E_{gap} =$  Band gap  
 $E_0 =$  Difference between NHE and vacuum  $\sim -4.5$  eV

M. A. Butler and D. S. Ginley, Journal of The Electrochemical Society (1978)

Y Xu and MAA Schoonen, American Mineralogist (2000)



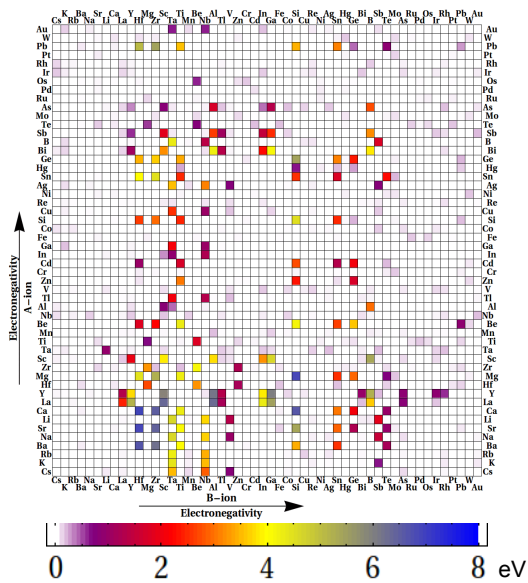
# Perovskites: Heat of formation



Stable materials:

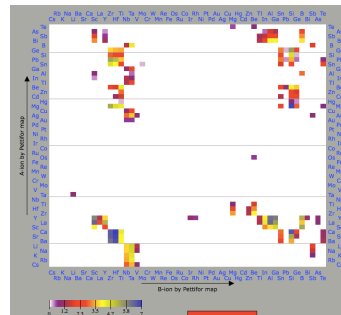
- Low electronegativity
- Sum of oxidation numbers = 6
- Geometric tolerance factor  $\sim 1$

# Perovskites: Band gaps

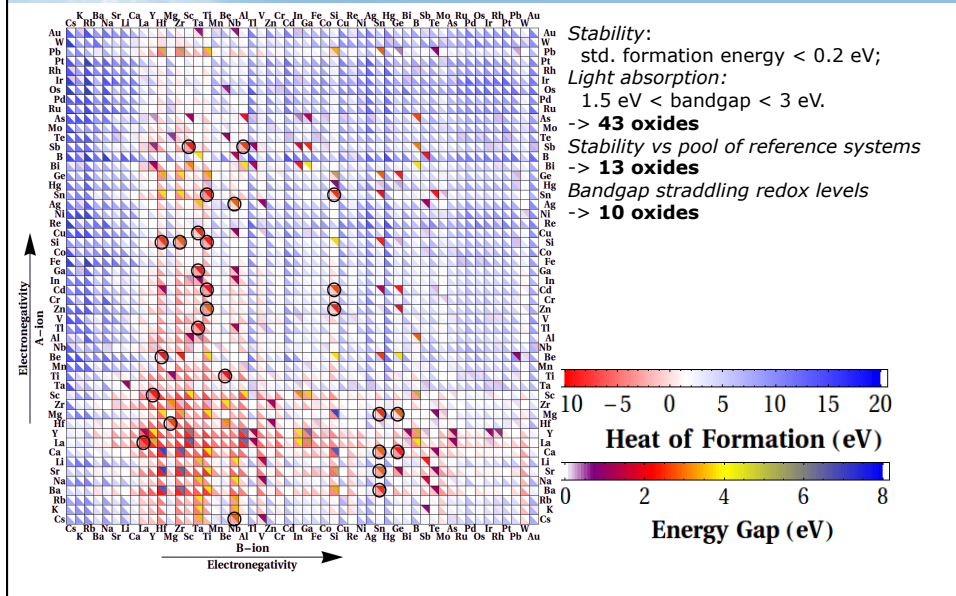


Most perovskites are metallic or low-gap semiconductors

Using "Pettifor-stringing" of periodic table



# Perovskites: ABO<sub>3</sub> candidates



# Perovskites: ABO<sub>3</sub> WS candidates (II)



Screening parameters	One-photon WS
Chemical/structural stability ( $\Delta E$ )	$\Delta E \leq 0.2$ eV
Bandgap ( $E_{\text{gap}}$ )	$1.5 \leq E_{\text{gap}} \leq 3$ eV
Band edges ( $VB_{\text{edge}}, CB_{\text{edge}}$ )	$VB_{\text{edge}} > 1.23$ eV $CB_{\text{edge}} < 0$ eV

AgNbO<sub>3</sub> and BaSnO<sub>3</sub> are known:  
AgNbO<sub>3</sub>: works (with low efficiency)

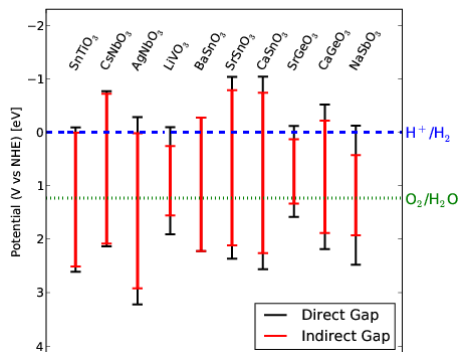
BaSnO<sub>3</sub>: defect induced recombination.

SrSnO<sub>3</sub> and CaSnO<sub>3</sub>: orthorhombic perovskite (too large bandgap).

None of the others are known.

Attempts to investigate LiVO<sub>3</sub> at CINF/DTU

10 oxides fulfill the criteria:

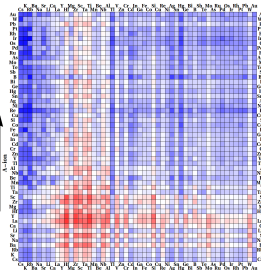


(Castelli, Olsen, Datta, Landis, Dahl, Thygesen, Jacobsen, Energy Environ Sci 5, 5814 (2012))

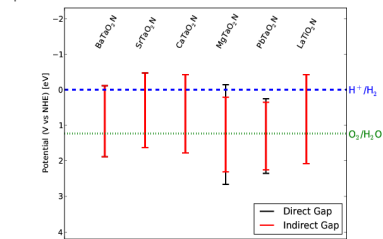
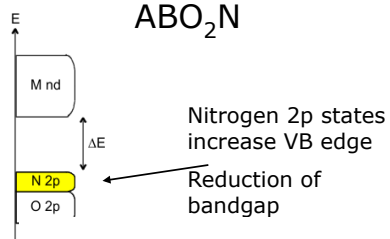
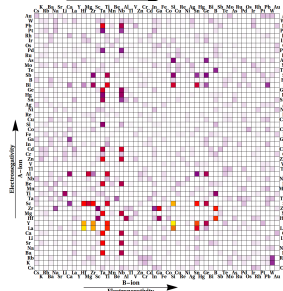
# Perovskite oxynitrides



Stability



Bandgap



**5 materials for water splitting**

Known: BaTaO<sub>2</sub>N, SrTaO<sub>2</sub>N, CaTaO<sub>2</sub>N, LaTiO<sub>2</sub>N

Unknown: MgTaO<sub>2</sub>N

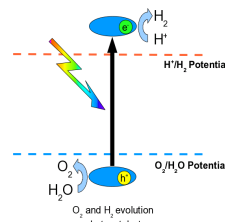
# Oxides, oxynitrides, oxysulfides, oxyfluorides, oxyfluornitrides



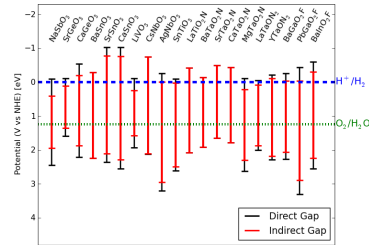
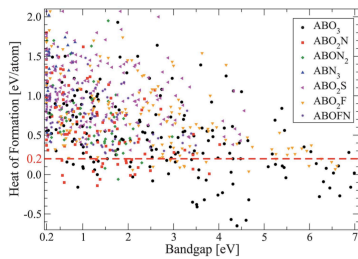
Materials candidates:

- ABO<sub>3</sub> :10
- ABO<sub>2</sub>N :5
- ABON<sub>2</sub> :2 LaTaON<sub>2</sub> (known)  
YTaON<sub>2</sub> (unknown)
- ABN<sub>3</sub> :0
- ABO<sub>2</sub>S :0
- ABO<sub>2</sub>F :3
- ABOFN :0 ~19000 materials

One-photon water splitting

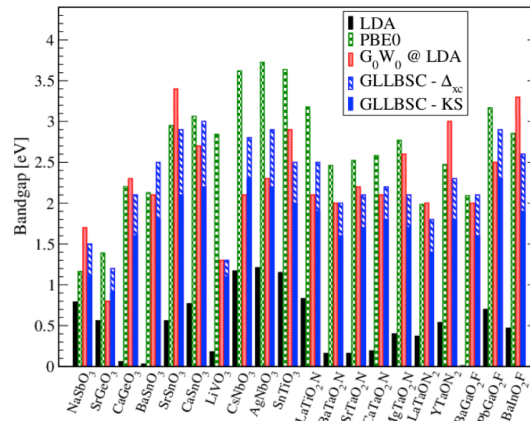


20 candidate materials



(Castelli, Landis, Thygesen, Dahl, Chorkendorff, Jaramillo, Jacobsen, Energy Environ Sci 5, 9034 (2012))

## Further analysis of candidate materials: bandgap calculations

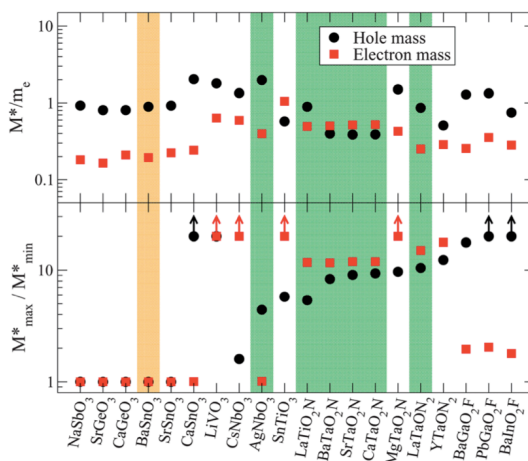


$G_0W_0$  on top of LDA  
using plasmon pole  
approximation

GLLBSC –  $G_0W_0$  mean absolute deviation 0.3 eV

Castelli, Garcia-Lastra, Hüser, Thygesen, Jacobsen, New Journal of Physics 15, 105026 (2013)

## Further analysis of candidate materials: mobilities – e/h band-masses



$$\frac{1}{M^*} = \frac{1}{3} \left( \frac{1}{m_x^*} + \frac{1}{m_y^*} + \frac{1}{m_z^*} \right)$$

**Green systems:** known to split water (with sacrificial reagents)

**Orange system:** BaSnO<sub>3</sub> known not to work (probably defect-assisted recombination)

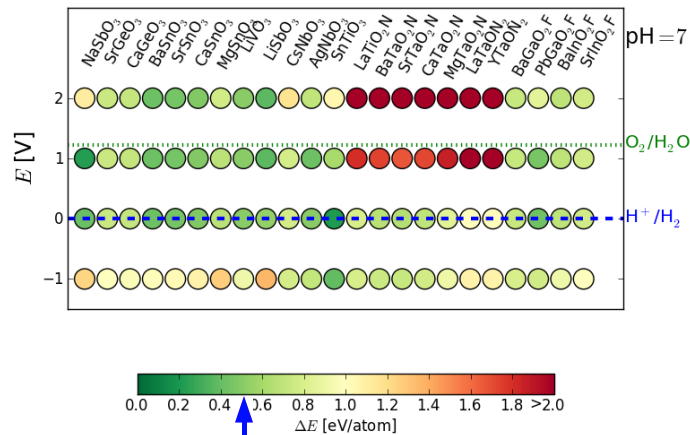
Systems observed to work so far seems fairly isotropic

## Further analysis of candidate materials: stability in water



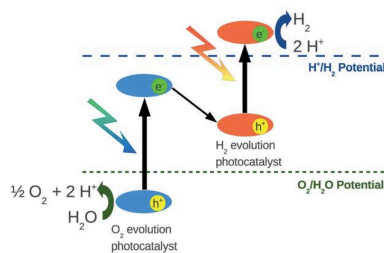
Oxides and oxyfluorides have a region where they are stable (with 0.5 eV threshold).

Oxynitrides are less stable, especially at high potential.



New stability threshold to include some metastability/kinetics and perhaps inaccuracies in the calculations.

## Tandem cell principle



Two semiconductors – two photons

- SC 1: Hole for oxygen evolution
- SC 2: Electron for hydrogen evolution

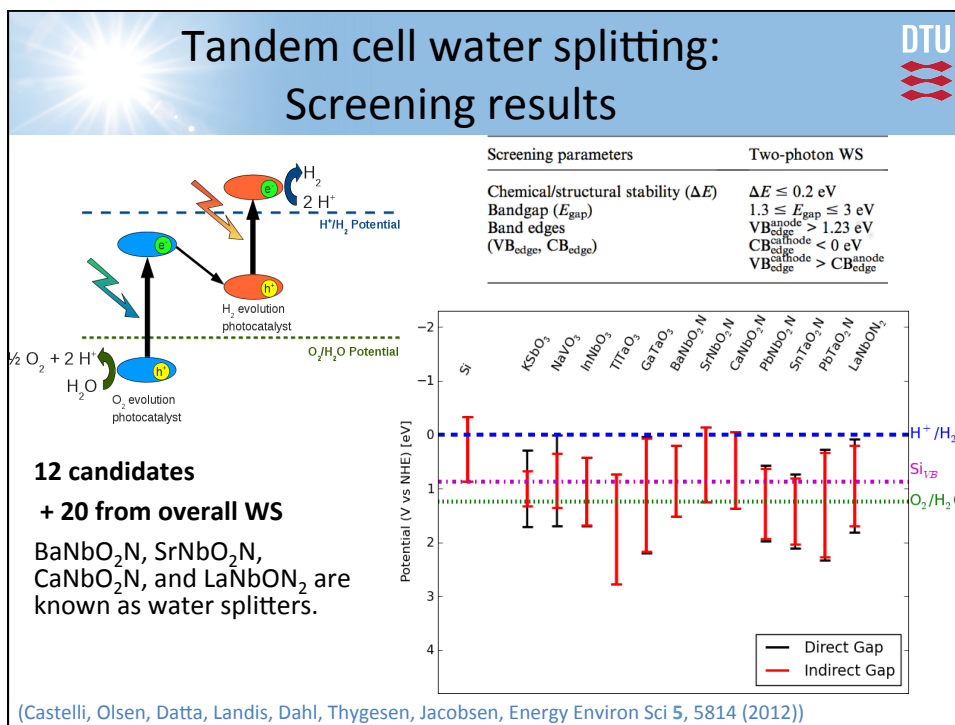
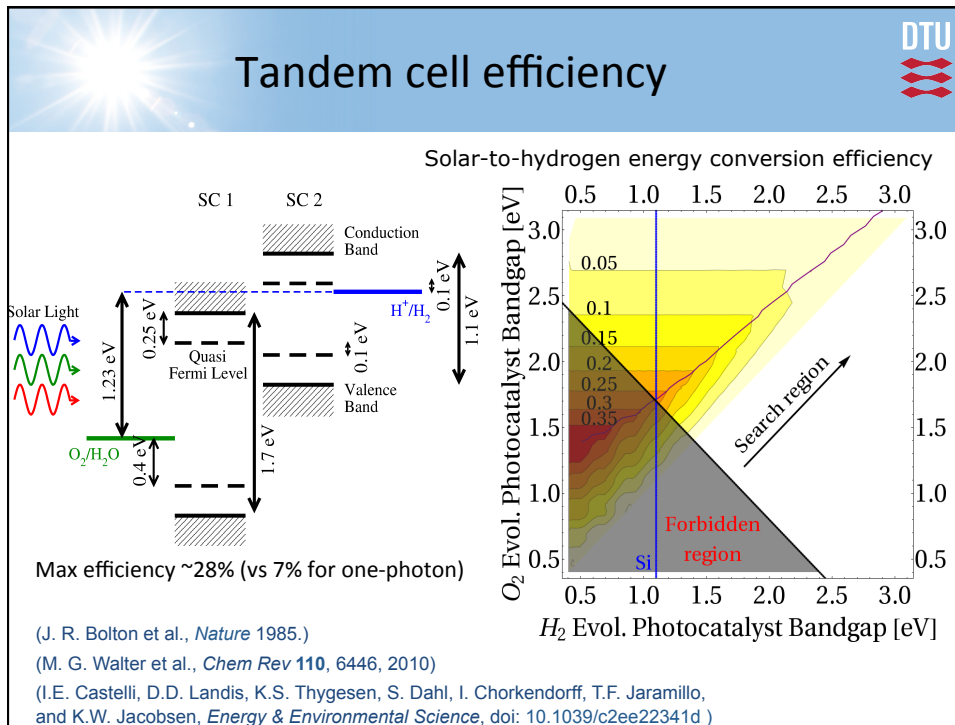
Requirements:

- structural/chemical stability;
- two visible light harvests (optimal gaps: 1.1 eV and 1.7 eV);
- band edges that match with oxygen and hydrogen potentials;
- Small overlap between the semiconductors band edges for the electron transfer reaction.

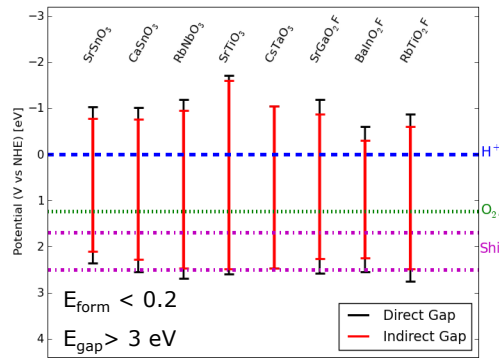
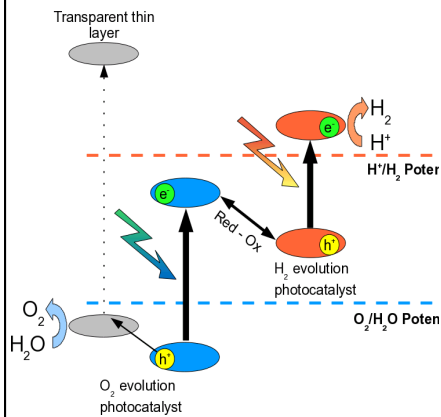
H<sub>2</sub> photocatalyst: Si

O<sub>2</sub> photocatalyst: screening





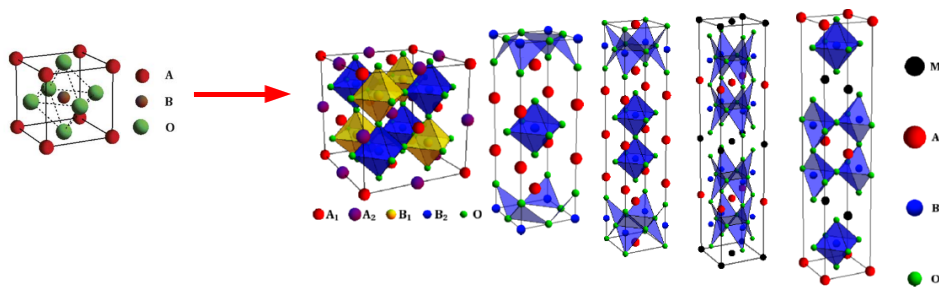
# Transparent protecting shield – photoanode



SrTiO<sub>3</sub> known for water splitting in UV light.  
SrSnO<sub>3</sub> and CaSnO<sub>3</sub> known in the orthorhombic phase.

Example: TiO<sub>2</sub> can be used to protect MoS<sub>2</sub> for hydrogen evolution  
(Seger et al., JACS, **135**, 1057 (2013)).

# Towards low-symmetry perovskites



Cubic (5 atom/cell)

Double (20)

Ruddlesden-Popper (14-24)

Dion-Jacobson (22-44)

Too expensive to run “brute force” screening for low symmetry structures.

Use three chemical-based rules derived from cubic perovskites:

- 1) Even-odd rule: Even number of electrons in unit cell to have a bandgap
- 2) Valence rule: Sum of possible valences should add up to zero.
- 3) Radius rule: Radius(A) > Radius(B)

Castelli and Jacobsen, Modelling Simul. Mater. Sci. Eng. **22**, 055007 (2014)

# “Traditional” rules not good enough

## Example: tolerance factor

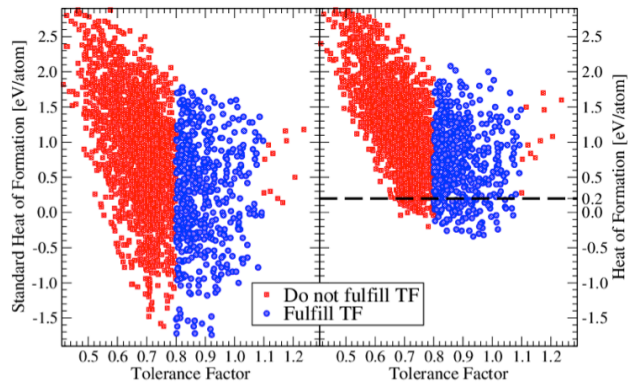


Tolerance factor:

$$t = \frac{r_A + r_O}{\sqrt{2}(r_B + r_O)}$$

Traditional rule:

$$0.8 < t < 1.1$$



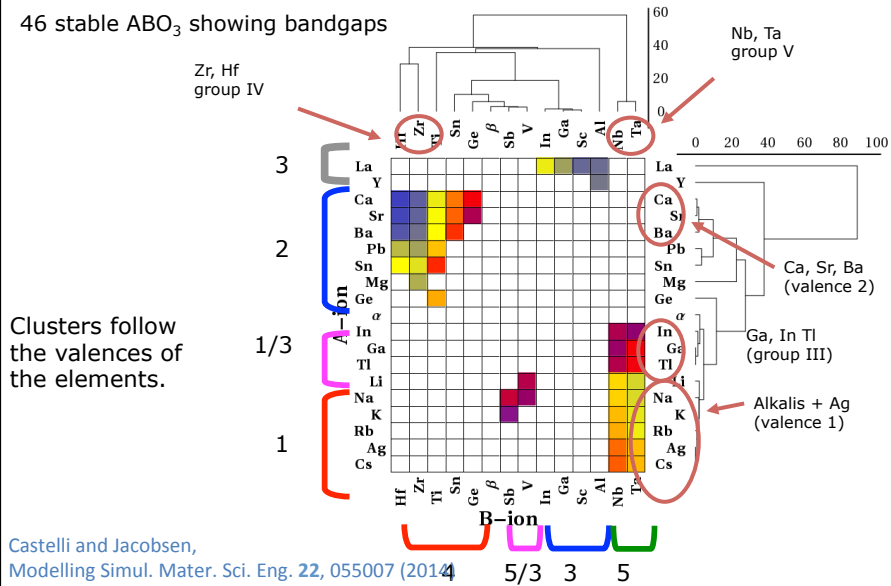
Example:  $\text{AgNbO}_3$  has  $t$  outside  $[0.8, 1.1]$

Castelli and Jacobsen, *Modelling Simul. Mater. Sci. Eng.* **22**, 055007 (2014)

# Cluster analysis based on bandgap for $\text{ABO}_3$ : Valence rules!



46 stable  $\text{ABO}_3$  showing bandgaps



Clusters follow the valences of the elements.

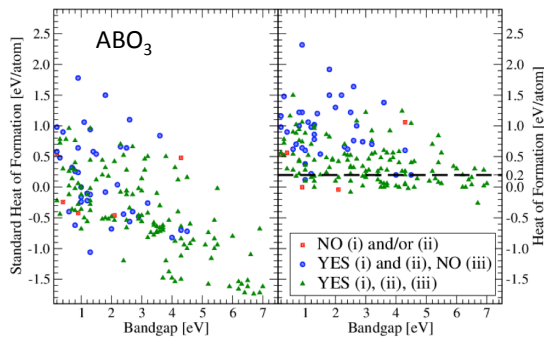
Castelli and Jacobsen, *Modelling Simul. Mater. Sci. Eng.* **22**, 055007 (2014)

# Fulfillment of chemical rules



Use three chemical-based rules derived from cubic perovskites:

- 1) Even-odd rule: Even number of electrons in unit cell to have a bandgap
- 2) Valence rule: Sum of possible valences should add up to zero.
- 3) Radius rule: Radius(A) > Radius(B)



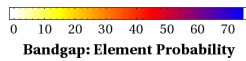
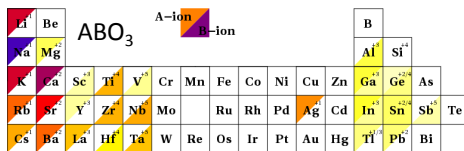
Simulations to run:  
 - No rules: 2704;  
 - With i and ii: 778;  
 - With all rules: 547.

Only three combinations are interesting but do not fulfill the rules

Rules transferable to oxynitrides -> only 16% satisfy rules

Castelli and Jacobsen, Modelling Simul. Mater. Sci. Eng. 22, 055007 (2014)

# Propensity and chemical rules



Probabilities and rules transferable to oxynitrides:

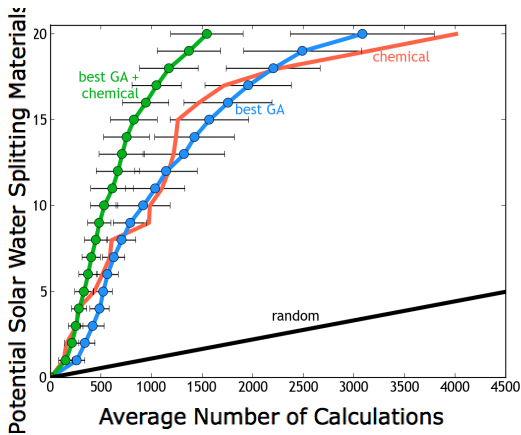
$$\tilde{P}(ABO_2N) = P_A(A)P_B(B)P_{\text{rules}}(ABO_2N)$$

Probability for an element to generate a stable semiconductor for the ABO<sub>3</sub> stoichiometry

A-ion	B-ion	Stable?	Gap [eV]	A-ion	B-ion	Stable?	Gap [eV]
Ca	Ta	✓	2.2	(cont.)			
Sr	Ta	✓	2.1	In	Hf		0
Ca	Nb	✓	1.4	La	Sn		1.8
Sr	Nb	✓	1.4	In	Ti		0
Ba	Ta	✓	2.0	La	Ge		0
Ba	Nb	✓	1.3	Y	Zr		3.3
La	Zr	✓	3.4	Ge	Ta		1.8
La	Hf	✓	3.8	Ge	Nb		1.1
La	Ti	✓	2.5	Y	Hf		3.4
Sn	Ta	✓	1.2	In	Sn		0
Sn	Nb	✓	0.5	Y	Ti		2.4
Pb	Ta	✓	2.0	Sn	Sb		0
Pb	Nb	✓	1.3	Pb	Sb		0
Sr	Sb		0	Sn	V		0
Ca	Sb		0	Pb	V		0
Sr	V		0	In	Ge		0
Ca	V		0	Mg	Sb		0
In	Zr		0	Mg	V		0
Mg	Ta	✓	2.1	Y	Sn		2.7
Mg	Nb		1.5	Y	Ge		1.3
Ba	Sb		0	Ge	Sb		0
Ba	V		0	Ge	V		0

Castelli and Jacobsen, Modelling Simul. Mater. Sci. Eng. 22, 055007 (2014)

# Evolutionary algorithm

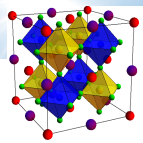


An evolutionary algorithm performs as good as a chemical-based search (rules i and ii).

Applying the chemical rules, the evolutionary algorithm shows a significant improvement.

A. Jain, I. E. Castelli, G. Hautier, D. H. Bailey, and K. W. Jacobsen, *Journal of Materials Science* **48**, 6519 (2013).

# Bandgap engineering: Double perovskites



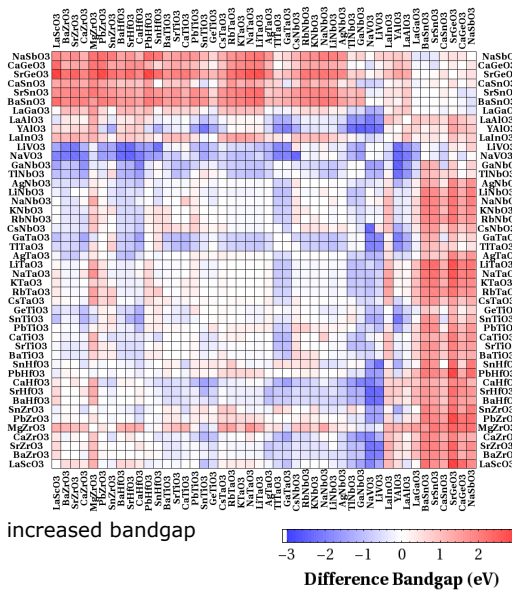
● A1 ● A2 ● B1 ● B2 ● O

Difference between the double perovskite bandgap and the average gap coming from the two constituent cubic perovskites

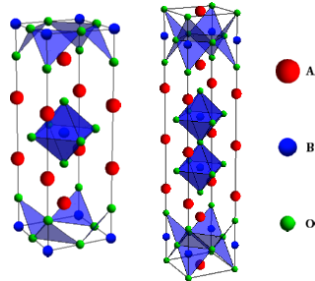
New "design rules":

- Double perovskite has average of perovskite gaps
- But, for B1 p-metal and B2 d-metal gap is significantly increased
- B1-ion(d) - B2-ion(p) hybridization -> increased bandgap

I. E. Castelli, K. S. Thygesen, and K. W. Jacobsen, *MRS Online Proceedings Library* **1523** (2013).



# Bandgap engineering: Layered perovskites (Ruddlesden-Popper)

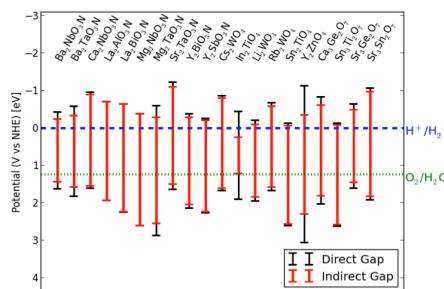


Bandgap decreases with the thickness of the octahedron layer when p-metals are in the B-position. Opposite for d-metals.

Criterion	One-photon WS	Two-photon WS
Stability ( $\Delta E$ )	$0.2 \text{ eV atom}^{-1}$	$0.2 \text{ eV atoms}^{-1}$
Bandgap ( $E_{\text{gap}}$ )	$1.7 \leq E_{\text{gap}} \leq 3$	$1.3 \leq E_{\text{gap}} \leq 3$
Band edges	$\text{VB}_{\text{edge}} > 1.6$	$\text{VB}_{\text{edge}}^{\text{anode}} > 1.6$
( $\text{VB}_{\text{edge}}, \text{CB}_{\text{edge}}$ )	$\text{CB}_{\text{edge}} < -0.1$	$\text{CB}_{\text{edge}}^{\text{cathode}} < -0.1$ $\text{CB}_{\text{edge}}^{\text{anode}} < \text{VB}_{\text{edge}}^{\text{cathode}}$

I. E. Castelli, J. M. Garcia-Lastra, F. Huser, K. S. Thygesen, and K. W. Jacobsen, *New J. Phys.* **15**, 105026 (2013).

More candidates for water splitting:

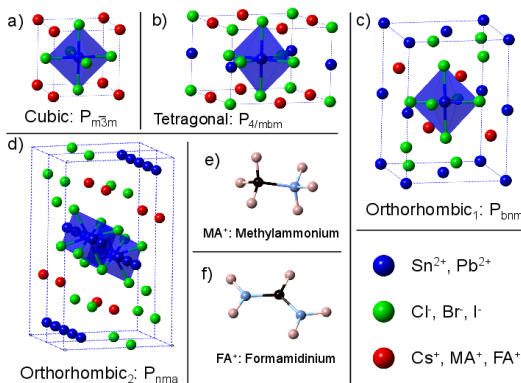


# Organic halide perovskites



$\text{CH}_3\text{NH}_3\text{PbI}$  based solar cells show up to 15% power conversion efficiency

(Burschka et al. *Nature* **499**, 316 (2013))



Properties:

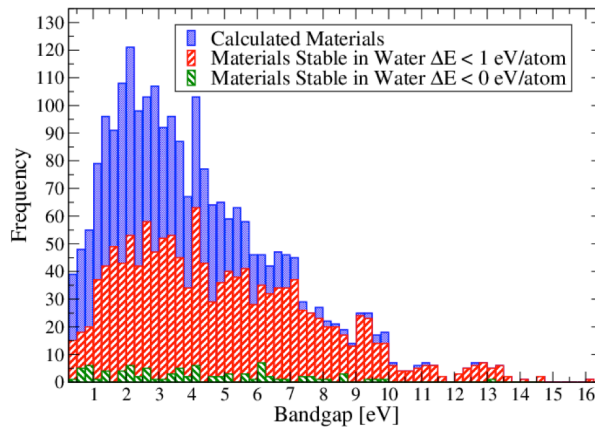
- Direct bandgaps
- Large absorption coefficients
- High carrier mobilities

240 possible combinations

# Screening for WS materials based on Inorganic Crystal Structure Database (ICSD)



Bandgaps of 2400 materials from ICSD



(Collaboration with Materials Project)

Castelli, Hüser, Pandey, Li, Seger, Thygesen, Jain, Persson, Ceder, Jacobsen, in preparation.

# Screening for one-photon water splitting based on ICSD



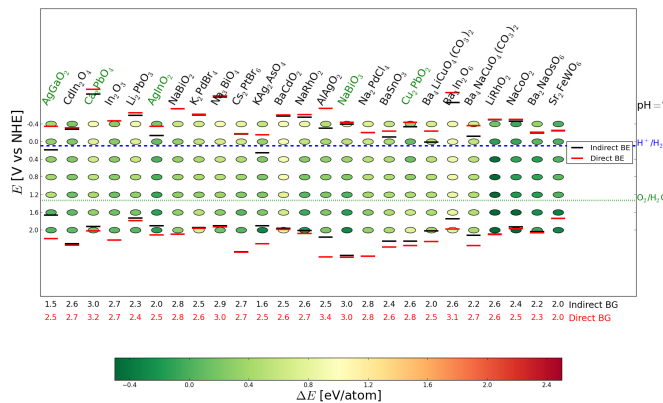
Stability in water at  $-0.4 < V < 2.0$

Bandgap:  $1.7 \text{ eV} < E_{\text{gap}} < 3.0 \text{ eV}$

Band edge positions:

$CB_{\text{edge}} < -0.1 \text{ vs NHE}$

$Vb_{\text{edge}} > 1.6 \text{ eV vs NHE}$



Some do not work:  $\text{Ba}_2\text{NaOsO}_6$  Mott insulator,  $\text{BaSnO}_3$  has a bandgap  $\sim 3.1\text{-}3.3 \text{ eV}$

Some are known in other contexts:  $\text{Ca}_2\text{PbO}_4$ ,  $E_{\text{gap}} \sim 1.8 \text{ eV}$  steel primer

Interesting candidates noted in green.

(Collaboration with Materials Project)

(Castelli, Hüser, Pandey, Li, Seger, Thygesen, Jain, Persson, Ceder, Jacobsen, in preparation)

# Computational Materials Repository



A system for storing/uploading, analyzing, retrieving, and sharing computational data.

Some ideas:

Many interfaces (sql, python, web, "silo")

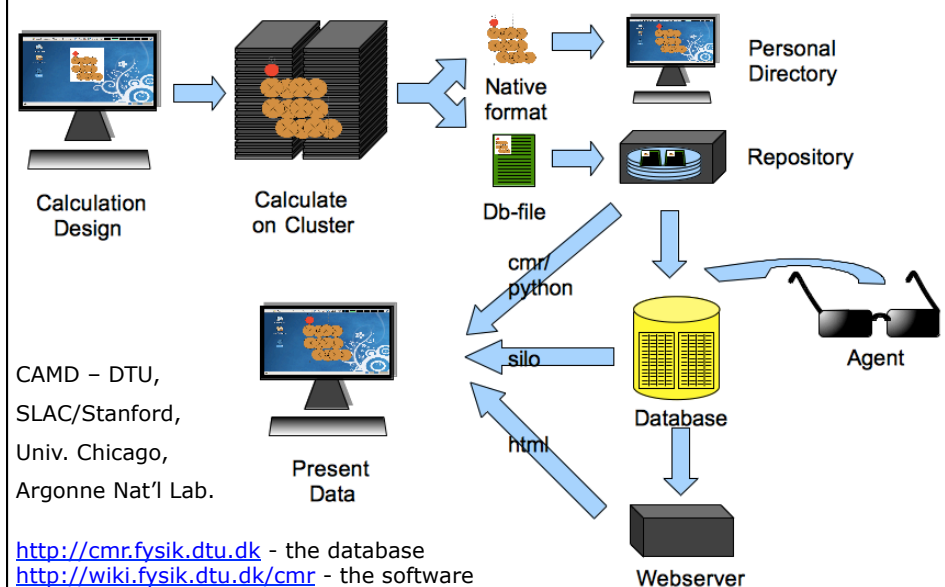
Agents – small pieces of code automatically performing calculations in the database

Taxonomy/folksonomy

<https://wiki.fysik.dtu.dk/cmr>

(Landis, Hummelshøj, Nestorov, Greeley, Dulak, Bligaard, Nørskov, Jacobsen, Comp. Sci. Eng. 14, 51 (2012))

# Computational Materials Repository





# Generic data view



related keyword

Found 2704 results (0.470712s)

Fields

id	ref	inst	A	B	anion	heat_of_formation	gibbs_dir_gap	gibbs_ind_gap	gibbs_ind_gap	dir CB	dir VB	dir VB	ind atoms	db keywords	doi	ingredients	downloads
1024			Rh	Ca	O3	1.0400	0	0	5.9347	5.9347	5.9347	0	10.1039/C1EE02717D	ABO3 max O O3	10.1039/C1EE02717D	0.25 Rh4 + 3.00 O	172
8835			Rh	Ag	O3	2.3700	0	0	6.0569	6.0569	6.0569	0	10.1039/C1EE02717D	ABO3 max O O3	10.1039/C1EE02717D	0.25 Rh4 + 3.00 O + 0.25 Ag4	172
8838			Rh	Ca	O3	1.5200	0	0	6.0182	6.0182	6.0182	0	10.1039/C1EE02717D	ABO3 max O O3	10.1039/C1EE02717D	0.50 Co2 + 0.25 Rh4 + 3.00 O	172
8945			Rh	Cu	O3	1.9100	0	0	6.0677	6.0677	6.0677	0	10.1039/C1EE02717D	ABO3 max O O3	10.1039/C1EE02717D	0.25 Rh4 + 3.00 O + 0.25 Cu4	172
8946			Rh	Si	O3	1.1400	0	0	6.1417	6.1417	6.1417	0	10.1039/C1EE02717D	ABO3 max O O3	10.1039/C1EE02717D	0.25 OSi4 + 0.25 Rh4 + 1.00 O	172

# Computational Materials Repository Project-specific web-interface



## Computational Materials Repository

Hide search box

Do not forget to press **update matrix** after changing the selection!

If there is an error - It means that the dataset is already being calculated! Please wait a moment and try again.

Chose a data set: ABO3 (2704)

Width: 800

Height: 1200

X axis ticks: B

Y axis ticks: automatically selected

X sort order: Electronegativity (Paulin)

Y sort order: Electronegativity (Paulin)

Action on Click: show band edges

References:  
 ABN (3)  
 ABO (20)  
 AN (50)  
 AO (52)  
 AOW (53)  
 default (3)  
 mbulk (52)

Value field:  
 Triangle 1: (top-right) gibbs\_ind\_gap (eV) 0->white,0.7->purple,2.2->red  
 Triangle 2: (bottom-left) heat\_of\_formation (eV) min->red,0.3->white,4->blue  
 Triangle 3:  
 Triangle 4:

Colors:  
 0->white,1->red,7->blue  
 0->white,0.9->red,2.2->green,4->yellow,8->blue  
 -100->blue,100->red

Valid color names are black, blue, cyan, green, gray, green, lightblue, pink, red, purple, white, yellow. Please note that the values must be in **increasing** order.

Update matrix

Link to image

band\_plot.php?PDBImage=100+1000+predef: Scaled 87% - Mozilla Firefox

192.168.56.182:~/cmr/modules/enhancement/band\_plot/band\_plot.php?db=TiTaO3&tab=Overview&gap\_dir=Dir&gap\_ind=Ind&ref=

TiTaO<sub>3</sub>  
 Heat of Form. = 0.1 eV/atom  
 Indirect Gap = 2.0 eV  
 Direct Gap = 2.0 eV  
 Valence Band = 2.8 (2.8) eV  
 Center Band = 1.8 eV  
 Conduction Band = 0.8 (0.8) eV

Legend:  
 - Direct Gap  
 - Indirect Gap

<http://cmr.fysik.dtu.dk> - the database

<http://wiki.fysik.dtu.dk/cmr> - the software, Publication to appear in Comp. Sci. Eng.

## Outlook



- Material screenings (stability and bandgap)
  - Learn trends and new chemical rules, info transfer
  - Build up useful (hopefully) materials databases
  - Find specific materials
- Challenges
  - Absorption spectra
    - Matrix elements
    - Excitonic effects
  - Mobilities (so far only band masses)
  - Defects
  - Surfaces/level alignments (so far empirical formula)
  - Nanostructuring
  - Catalysis (SC surface or co-catalysts?)

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Gebrand Ceder

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Kristin Persson

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Søren Dahl

Peter Vesborg

Ib Chorkendorff

### **Stanford:**

Tom Jaramillo

CASE

Catalysis for Sustainable Energy

